

Electronic Supplementary Information

# **Development of a novel method to grow MoS<sub>2</sub> mono/few-layer films and MoS<sub>2</sub>-graphene hybrid films for supercapacitor applications†**

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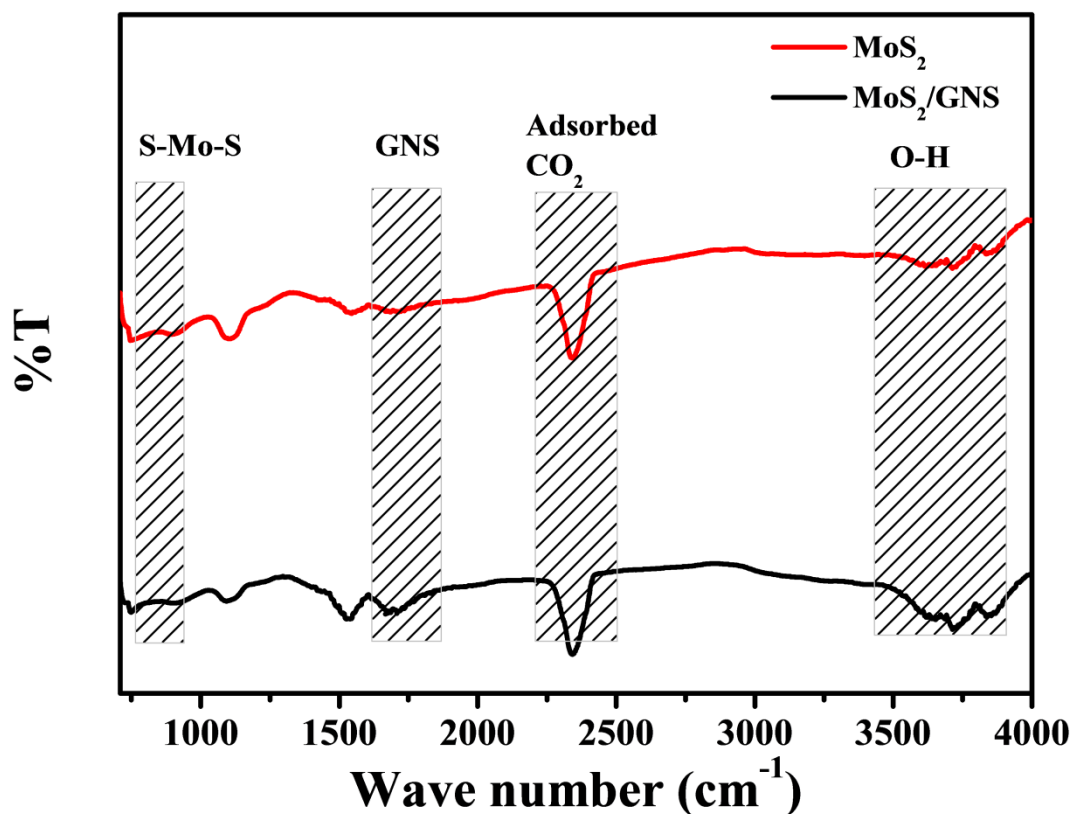


Fig. S1. Fourier transform infrared spectra of MoS<sub>2</sub> nanosheets and MoS<sub>2</sub>-GNS composites.

FT-IR spectra of MoS<sub>2</sub>-GNS composites were compared between 400 – 4000 cm<sup>-1</sup>. As shown in Fig. S1, in the FT-IR spectra, the bands between 3400 to 3700 cm<sup>-1</sup> are attributed to the oxygen containing functional groups of graphene.<sup>1</sup> The peak at 2260 cm<sup>-1</sup> were caused by CO<sub>2</sub> adsorbed in the sample.<sup>2</sup> Furthermore, the observed absorption band between “1620-1730 cm<sup>-1</sup>” for MoS<sub>2</sub>-GNS, indicates the skeletal vibration of graphene sheets.

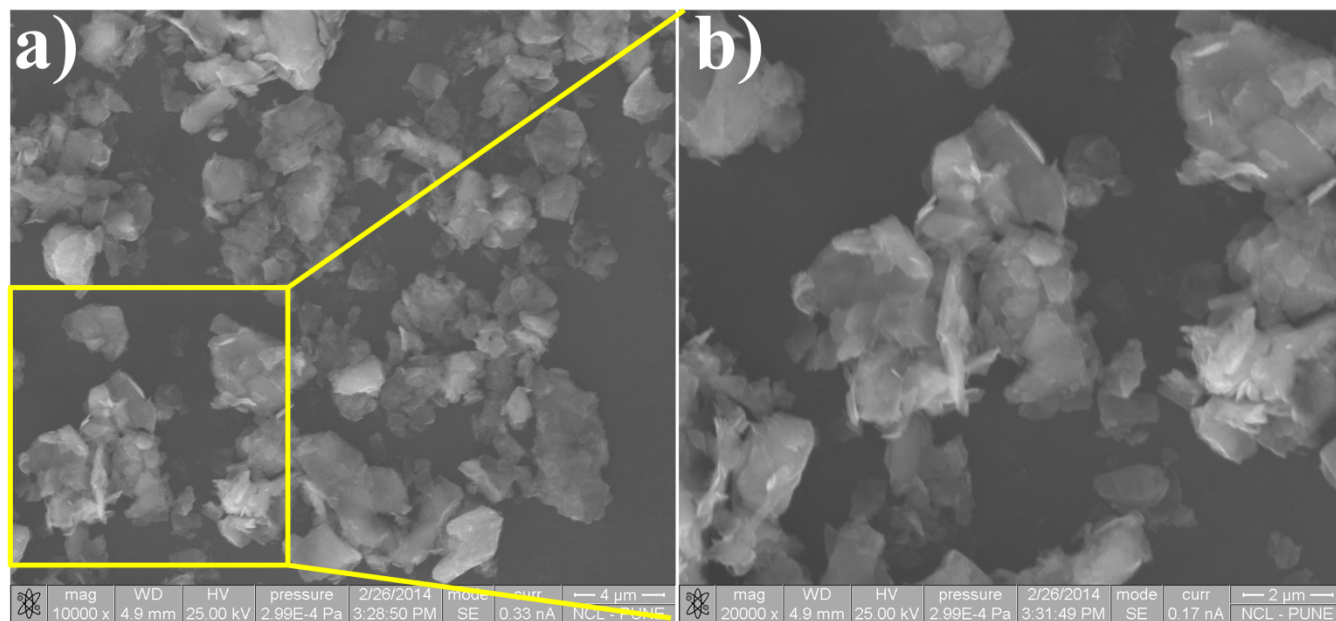


Fig. S2. SEM image of acid-intercalated exfoliated MoS<sub>2</sub> nanosheets deposited on Si wafer.

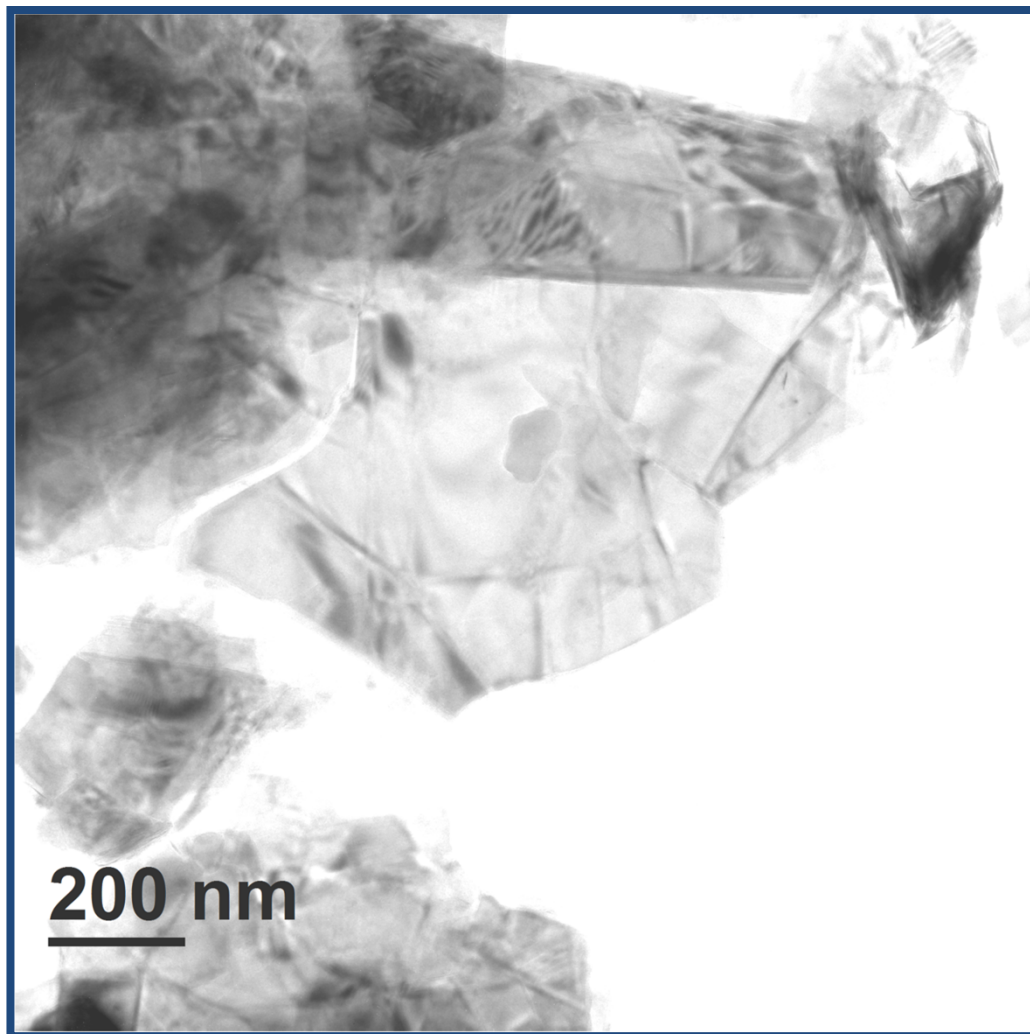


Fig. S3. HRTEM of MoS<sub>2</sub> image display the curved graphene like morphology at low magnification.

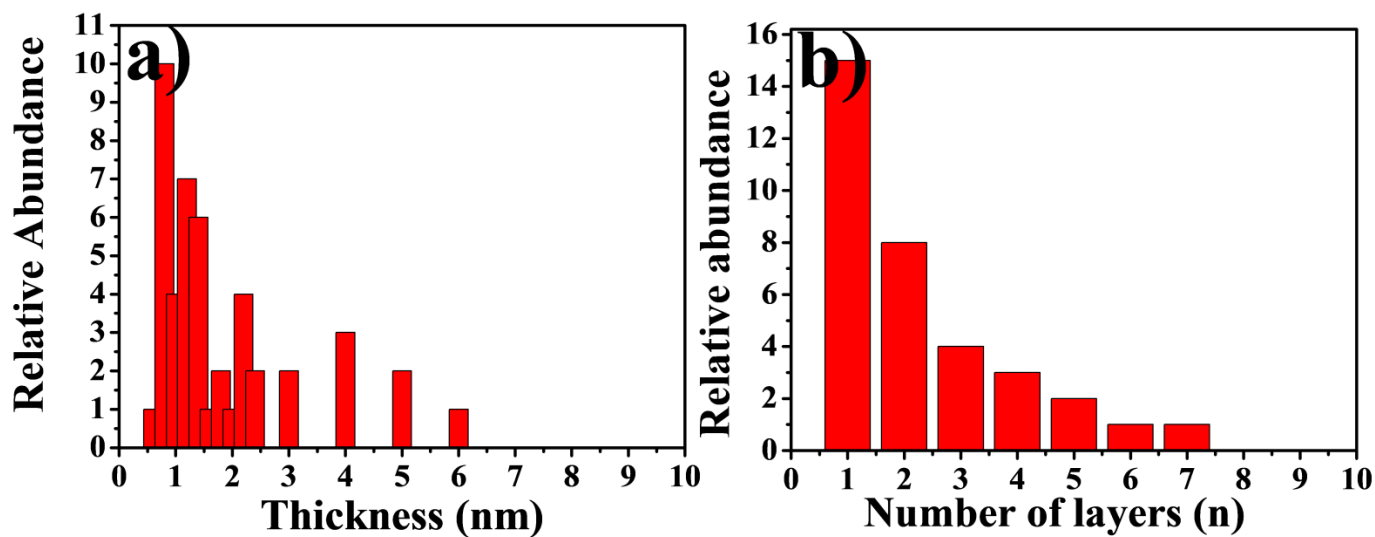


Fig. S4. Thickness distribution based on 50 randomly selected 2D nanosheets of MoS<sub>2</sub> in the AFM topographic image, Fig. 4a.

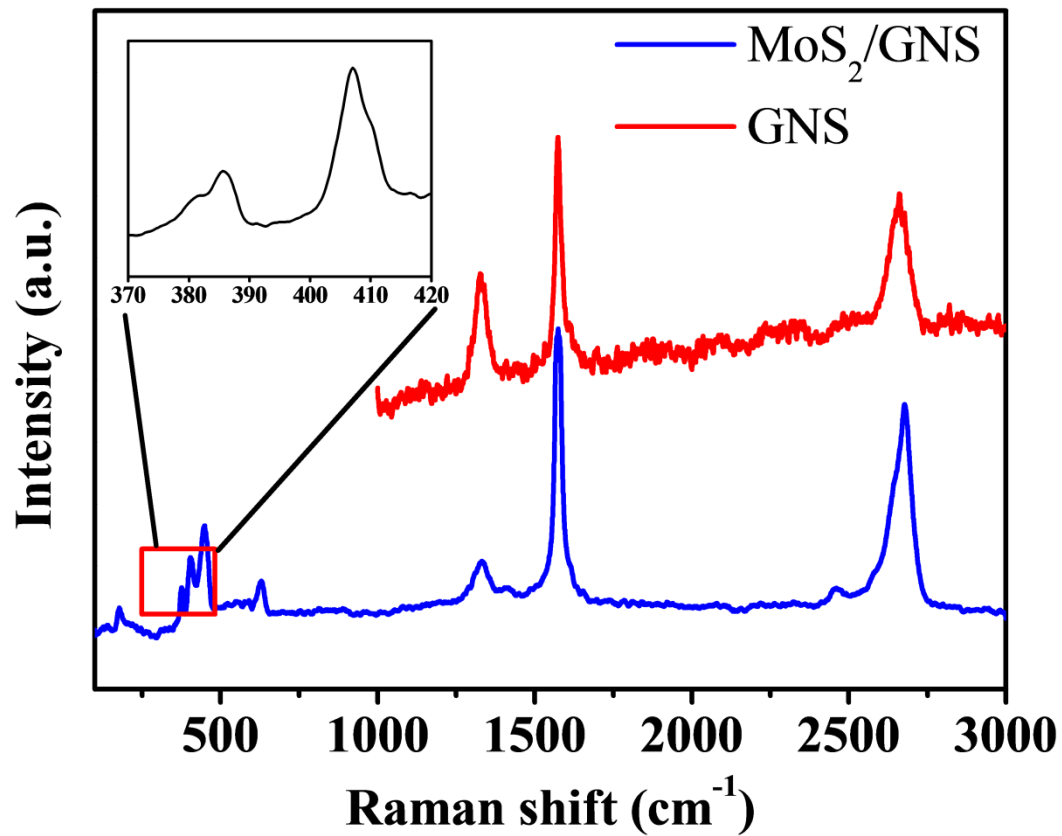


Fig. S5 Raman spectra of GNS and MoS<sub>2</sub>-GNS composite

Table S1:

Scan Rate	Specific capacitance $Fg^{-1}$ from Cyclic Voltametry				% Retention
	20mVs-1	50 mVs-1	100 mVs-1	150 mVs-1	
MoS <sub>2</sub>	155	153	124	108	69%
MoS <sub>2</sub> /GNS	282	169	152	141	85%

Table S2:

Current Density	Specific capacitance $Fg^{-1}$ from Galvanostatic charge discharge				% Retention
	20 $\mu$ A	40 $\mu$ A	60 $\mu$ A	80 $\mu$ A	
MoS <sub>2</sub>	156	152	147	144	92.3%
MoS <sub>2</sub> /GNS	255	243	240	236	92.5%

## References

1. K.-J. Huang, L. Wang, Y.-J. Liu, Y.-M. Liu, H.-B. Wang, T. Gan and L.-L. Wang, *J of Hydrogen Energy*, 2013, **38**, 14027.
2. G. Huang, T. Chen, W. Chen, Z. Wang, K. Chang, L. Ma, F. Huang, D. Chen and Y. Lee, *Small*, 2013, **9**, 3693.